TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG32FE

### 2 Input OR Gate

#### **Features**

• High-level output current: I<sub>OH</sub>/I<sub>OL</sub> = ±8 mA (min)

at  $V_{CC}$  = 3.0 V

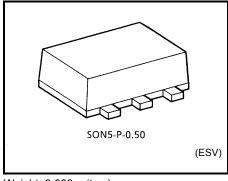
• High-speed operation: t<sub>pd</sub> = 2.4 ns (typ.)

at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

• 5.5-V tolerant inputs.

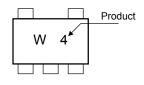
• 3.6-V power down protection output.

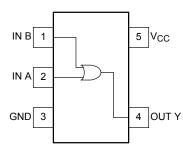


Weight: 0.003 g (typ.)

### Marking

### Pin Assignment (top view)





### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit			
Power supply voltage	Vcc	-0.5~4.6	V			
DC input voltage	V <sub>IN</sub>	-0.5~7.0	٧			
DC output voltage	V	-0.5~ 4.6 (Note 1)	V			
DC output voltage	Vout	-0.5~ V <sub>CC</sub> + 0.5 (Note 2)	V			
Input diode current	I <sub>IK</sub>	-20	mA			
Output diode current	lok	-20 (Note 3)	mA			
DC output current	I <sub>OUT</sub>	±25	mA			
DC V <sub>CC</sub> /ground current	Icc	±50	mA			
Power dissipation	$P_{D}$	150	mW			
Storage temperature	T <sub>stg</sub>	-65~150	°C			

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0V$ 

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: Vout < GND

TC7SG32FE

# **IEC Logic Symbol**

IN B -

#### 

### **Truth Table**

Α	В	Υ
L	L	L
٦	Н	Н
I	L	Н
Τ	Н	Н

# **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V	0~3.6 (Note 4)	V	
	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 5)		
Output Current		±8.0 (Note 6)		
	I <sub>OH</sub> /I <sub>OL</sub>	±4.0 (Note 7)		
		±3.0 (Note 8)	A	
		±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 10:  $V_{CC} = 1.1 \sim 1.3 \text{ V}$ 

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

Note 12:  $V_{IN} = 0.8$ ~2.0 V,  $V_{CC} = 3.0$  V

# **DC Electrical Characteristics**

Characteristics Symbol Test Condition			Condition		Ta = 25°C			Ta = -40~85°C		Unit	
ZZ.doto.iotico		1030	V <sub>C</sub>		Min	Тур.	Max	Min	Max	Oill	
				0.9	Vcc		_	Vcc			
				1.1~1.3	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	1		
High-level VIH input voltage	V <sub>IH</sub>	_		1.4~1.6	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65		V	
			1.65~1.95	V <sub>CC</sub> × 0.65		_	V <sub>CC</sub> × 0.65	1			
				2.3~2.7	1.7	_	_	1.7	_	1	
				3.0~3.6	2.0	_	_	2.0	_		
				0.9	_	_	GND	_	GND		
		_		1.1~1.3	_		V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	V	
Low-level	V <sub>IL</sub>			1.4~1.6	_	_	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35		
input voltage				1.65~1.95	_	_	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35		
				2.3~2.7	_	_	0.7		0.7		
				3.0~3.6	_	_	8.0		8.0		
High-level V <sub>OH</sub>		VIN = VIH	I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_	V	
			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75		_	V <sub>CC</sub> × 0.75	1		
	V <sub>OH</sub>		$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75			
			$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45			
			$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_		
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48	_		
		oL VIN = VIL	$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	V	
			I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25		
Low-level voltage	V <sub>OL</sub>		I <sub>OL</sub> = 1.7 mA	1.4~1.6	_		V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25		
			I <sub>OL</sub> = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45		
			I <sub>OL</sub> = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4		
			I <sub>OL</sub> = 8.0 mA	3.0~3.6	_		0.4	_	0.4		
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		0~3.6	_	_	±0.1	_	±1.0	μА	
Power off leakage current	l <sub>OFF</sub>	V <sub>IN</sub> = 0~5.5 V <sub>OUT</sub> = 0~3	5V 3.6V	0	_	_	1.0	_	10.0	μА	
Quiescent supply current	Icc	VIN = VCC	or GND	3.6	_	_	1.0	_	10.0	μΑ	

# AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
Ondracteristics			C <sub>L (</sub> pF)	Min	Тур.	Max	Min	Max	Offic
		$\begin{array}{c} C_L = 10 \ pF, \\ R_L = 1 \ M\Omega \end{array}$	0.9	_	17.0	_	_	_	
			1.1~1.3	_	8.8	18.4	1.0	34.2	
			1.4~1.6	_	5.0	8.5	1.0	10.0	
			1.65~ 1.95	_	3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.7	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
		$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	0.9	_	20.7		_	_	
	tpLH tpHL		1.1~1.3	_	10.6	21.5	1.0	37.2	ns
			1.4~1.6	_	5.9	9.3	1.0	11.2	
Propagation delay time			1.65~ 1.95	_	4.5	6.9	1.0	7.1	
			2.3~2.7	_	3.0	4.4	1.0	5.0	
			3.0~3.6	_	2.4	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	29.6	_	_	_	
			1.1~1.3	_	14.8	29.6	1.0	56.0	
			1.4~1.6	_	8.0	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	3.9	5.7	1.0	6.1	
			3.0~3.6	_	3.0	4.4	1.0	4.8	
Input capacitance	C <sub>IN</sub>		3.6	_	3	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 13)	0.9~3.6	_	6		_	_	pF

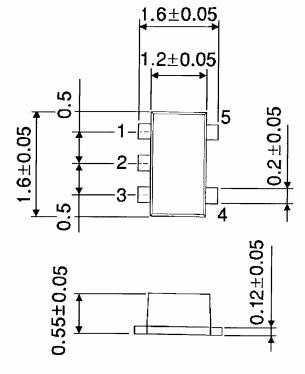
Note 13:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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